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Mechanism of Incorporation of Zinc into Hydroxyapatite

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Abstract

An atomic-level incorporation mechanism of Zn\textsuperscript{2+} in hydroxyapatite (HAp), which is a potential dopant for promoted bone formation, was investigated, based on first-principles total energy calculations and experimental x-ray absorption near edge structure (XANES) analyses. It was found that Zn\textsuperscript{2+}-doped HAp tends to have Ca deficient chemical composition and substitutional Zn\textsuperscript{2+} ions are associated with a defect complex of a Ca\textsuperscript{2+} vacancy and two charge-compensating protons. Moreover, first-principles calculations demonstrated that Zn\textsuperscript{2+} incorporation into HAp can take place through occupying the Ca\textsuperscript{2+} vacancy of the defect complex. The Ca\textsuperscript{2+}-vacancy complex is not only an origin of calcium deficiency of HAp, but will also play a key role for uptaking trace elements during mineralization.

Keywords: first-principles calculation, x-ray absorption spectrum, defect complex, formation energy, solution pH
1. Introduction

Hard tissues in bones are composed of inorganic calcium phosphate minerals and organic collagen fibrils, and the inorganic minerals play versatile and important roles such as mechanically supporting human bodies and storing or releasing calcium and other ions into body fluids to maintain homeostasis. Although hydroxyapatite (Ca$_{10}$(PO$_4$)$_6$(OH)$_2$, HAp) is a representative component of the inorganic part of bone, its chemical composition is generally rather complicated in reality: nonstoichiometric and calcium deficient (Ca/P molar ratio < 1.67) due to vacancies, foreign cations and anions such as sodium, zinc, magnesium, iron and carbonate (CO$_3^{2-}$) ions, which are uptaken from the surrounding body fluids during bone metabolism [1,2]. Foreign ions also control microstructures, crystallinity, and physicochemical properties, such as solubility and osteoconductivity, of HAp minerals. From a viewpoint of osteoporosis prevention, zinc and strontium ions are deliberately doped to promote bone formation and/or to retard bone absorption by their incorporation into HAp minerals [3,4]. Although the trace elements and dopants in HAp minerals will have individual roles in bone formation or bone remodeling processes, little is known about an incorporation mechanism of the foreign ions into HAp minerals and their local physical and chemical environments at an atomic-scale regime, relevant to biological HAp properties.

Among foreign ions commonly involved in HAp, the present study focuses on Zn$^{2+}$ incorporation into HAp, because Zn$^{2+}$ is a typical dopant to promote bone formation. However, there are a number of contradictory data on the Zn$^{2+}$ incorporation, and the experimental zinc solubility in HAp, previously reported, exhibits a wide variation ranging from a few to 15 mol% [5-7]. Even the essential solubility of Zn$^{2+}$ into HAp is still ambiguous, and thus it is of scientific importance to understand a detailed mechanism of the zinc incorporation. As the mechanism, it can be simply considered that Zn$^{2+}$ ions substitute for isovalent Ca$^{2+}$ ions in HAp. However, previous theoretical
investigations on Zn\textsuperscript{2+} substitution for Ca exhibited the quite limited solubility of at most 10\textsuperscript{-2} mol\%, i.e., energetically unfavorable, which indicates that Zn\textsuperscript{2+} incorporation is not necessarily explained by the simple substitution mechanism [8]. On the other hand, many of previous experiments showed that Zn\textsuperscript{2+}-doped HAp precipitated from aqueous solutions often contain a certain amount of Ca\textsuperscript{2+} vacancies, namely the molar ratio of (Ca+Zn)/P < 1.67 [6,7,9,10]. Based on these results, it can be postulated that another mechanism involving Ca\textsuperscript{2+} vacancies will work in Zn\textsuperscript{2+} incorporation. Understanding the Zn\textsuperscript{2+} incorporation mechanism will become a definite step to explore the detailed Zn\textsuperscript{2+} effect on the promoted bone formation. In order to clarify this issue, therefore, the present study attempts to investigate the thermodynamic stability, the incorporation mechanism and the local chemical environment of Zn\textsuperscript{2+} in HAp, using first-principles total energy calculations and experimental XANES for model HAp samples. Special attention is paid for a Ca\textsuperscript{2+}-vacancy effect on Zn\textsuperscript{2+} incorporation.

2. Methods

2.1. Experimental Procedure

Zn\textsuperscript{2+}-doped HAp samples were also synthesized by precipitation using 0.1 M Ca(NO\textsubscript{3})\textsubscript{2}·4H\textsubscript{2}O and 0.1 M (NH\textsubscript{4})\textsubscript{2}HPO\textsubscript{4} solutions. 0.1 M Zn(NO\textsubscript{3})\textsubscript{2}·6H\textsubscript{2}O solution was used as the zinc ion source, and a nominal Zn/(Ca+ Zn) molar ratio was set at 1 \%. Such a small amount of Zn\textsuperscript{2+} is based on the face that zinc is known to basically destabilize the HAp phase and thus more zinc addition may prevent producing single-phase Zn\textsuperscript{2+}-doped HAp. The solutions were mixed so as to produce samples with a stoichiometric (Ca+ Zn)/P molar ratio of 1.67, and were stirred for an hour while the solution pH is kept at pH = 10. NH\textsubscript{3} solutions were used to adjust pH values of the solutions. After one-hour maturation, the precipitated HAp powders were washed by
distilled water and were dried at 323 K for 24 hours. According to XRD analyses for the present samples, formation of HAp single phase was confirmed and no secondary phase such as tricalcium phosphate (TCP) was observed [11,12]. This fact was also the case after annealing in air at 773 K, and then there was no pronounced difference in XRD and XANES profiles between before and after annealing, which indicates that doped Zn ions are not simply adsorb on HAp surfaces but are indeed incorporated into the HAp lattice. Chemical analyses were performed by inductively coupled plasma atomic emission spectroscopy (ICP-AES). The resultant (Ca+Zn)/P molar ratio was found to be 1.51, which indicates the Ca vacancies of less than 10 % involved in the samples. The molar ratio of the doped sample was still smaller than that of the undoped sample (Ca/P=1.63) produced by the same experimental condition. It can be thus speculated that Zn doping tends to induce more calcium deficiency in HAp. The similar trend of the decreased (Ca+Zn)/P ratio from stoichiometry in Zn$^{2+}$-doped HAp was also observed in previous studies [6,7].

For the Zn$^{2+}$-doped HAp samples thus obtained, Zn-K XANES was measured at the SPring-8 (Hyogo, Japan) [13]. The XANES data were collected with the fluorescent mode using the highly-sensitive 19-elements Ge solid states detector and the Si (311) double crystals to monochromate incident X-ray beams. It is well known that XANES generally reflects local atomic coordination and chemical bonding state for an atom of interest, and it is suitable, therefore, to analyze detailed chemical environment of Zn$^{2+}$ dissolving into HAp.

2.2. Computational Procedure

For theoretical analyses on thermodynamic stability of Zn$^{2+}$ in HAp, first-principles band-structure calculations were performed based on the projector
augmented method, implemented in VASP [14,15]. The generalized gradient approximation (GGA) proposed by Perdew et al. was used for the exchange-correlation potential [16]. Wave functions were expanded by plane waves up to a cutoff energy of 500 eV, and atoms were allowed to relax until forces on atoms converged to less than 0.05 eV/Å. Brillouin zone sampling was done at the Γ point for the HAp supercells described below. These computational conditions ensure a good computational accuracy of less than 1.0 meV/atom. At the beginning, HAp supercells containing 352 atoms were generated by doubling the hexagonal unit cell (space group $P6_3/m$) in three dimensions, and were used for the present defect calculations [2,17]. Using such a large supercell assumes the calculations in the dilute limit, which is advantageous to investigate essential dopant solubility in systems with relatively low concentrations.

In order to study the Zn$^{2+}$ substitution in Ca-deficient HAp, a Ca$^{2+}$ vacancy at Ca-2 (triangular Ca site about the OH$^-$ arrangement along the c axis) charge-compensating two protons (see Fig. 1(a)) was introduced into the supercell. This vacancy-proton defect complex (charge neutral) can be represented by $(V_{Ca}−2H_2)^{x}$, according to the Kröger-Vink notation, and was theoretically found to be the energetically most stable defect in HAp [18,19]. Experimentally, the inclusion of lattice water [7,20] and the preferential loss of Ca-2 [21] were also pointed out, which also suggests that the Ca-vacancy defect complex is a plausible defect model in Ca-deficient HAp. The perfect and Ca-deficient HAp supercells were used for calculations of Zn$^{2+}$ incorporation in HAp.

Based on total energies of HAp supercells ($E_T$), defect formation energies ($\Delta H_f$) were evaluated. If a Zn$^{2+}$ is introduced into HAp in some form of a neutral charge state, $\Delta H_f$ can be written as $\Delta H_f = E_{f}^{Zn} - E_{f}^{0} + \sum n_i \mu_i$. Here $E_{f}^{Zn}$ and $E_{f}^{0}$ indicate total energies for Zn$^{2+}$-doped and undoped supercells, respectively. $\mu_i$ is a chemical potential for an ionic species and $n_i$ is an integer corresponding to the numbers of the
ionic species to be removed from or added to the undoped supercell. In order to obtain $\Delta H_f$ for Zn$^{2+}$ in HAp, the chemical equilibrium of HAp with an aqueous solution saturated with respect to HAp and containing a particular concentration of Zn$^{2+}$ ([Zn$^{2+}$]) was assumed. In the present case, [Zn$^{2+}$] was set at $1.0 \times 10^{-3}$ mol/L, as found in previous solution-precipitation experiments. Ionic chemical potentials for respective ionic species were determined from total energies of pure substances, experimental standard ionic formation energies in solution, and the ionic concentrations in the saturated solution [8,22]. Since the ionic concentrations depend on solution pH, the ionic chemical potentials and subsequent defect formation energies also show the pH dependence. More detailed descriptions for evaluation of the ionic chemical potentials and defect formation energies can be found elsewhere [8,22].

Furthermore, theoretical Zn-K XANES spectra for Zn$^{2+}$-doped HAp were calculated by two kinds of first-principles methods within the GGA, the plane wave based pseudopotential method in the CASTEP code [23,24] and the full-potential augmented plane wave plus local orbital (APW+lo) method in the WIEN2k code [25]. The CASTEP calculations basically use ultrasoft pseudopotentials. In order to take account of a core-hole effect in electronic excitation, ultrasoft pseudopotentials designed for excited atoms with a core hole are employed in the CASTEP calculations. In the present case, the excited pseudopotential for Zn was adopted for an excited Zn atom involved in a HAp supercell. 88-atom HAp supercells (generated by doubling the hexagonal HAp unit cell along the c axis) were used for the spectrum calculations. A plane-wave cut off energy was set to be 400 eV, and Brillouin zone sampling was performed by the $2 \times 2 \times 1$ Monkhorst-Pack mesh [26]. In order to make comparison with experiment, photoabsorption cross section (PACS) from matrix elements of electric dipole transition between the core orbital (1s) of Zn and unoccupied ones was calculated. The PACS thus calculated was broadened by a Gaussian function with full widths at half maximum (FWHM) of 0.5 eV and 1.67 eV, to obtain theoretical spectra. The
theoretical transition energy was also calculated by the pseudopotential calculation of the supercell and the all-electron calculation of the isolated atom, as reported elsewhere [27].

On the other hand, in the WIEN2k calculations, the same computational conditions of the supercell size and \( k \)-point sampling were used. The plane wave cutoff of \( R_{MT}K_{\text{max}} \) (the muffin-tin radius \( R_{MT} \) and the maximum reciprocal space vector \( K_{\text{max}} \)) was fixed at 3.5 Bohr Ryd\(^{1/2}\). In this case, in order to include the core-hole effect, one electron was removed from a core orbital of an atom of interest, and was put at the bottom of the conduction band. Spectral profiles were obtained from the product of the radial part of the transition matrix element and the projected partial density of states for the electric-dipole allowed transition of interest. The total energy difference between the initial and the final state was used as the theoretical transition energy.

It is also noted that theoretical transition energies are generally different from experimental ones. In both kinds of the present spectrum calculations, therefore, Zn-K XANES for ZnO was calculated as a reference, and the transition-energy difference between theory and experiment was used for correction of the calculated spectra for Zn defects in HAp, which corresponds to -39.7 eV for the pseudopotential method (CASTEP) and -42.7 eV for the APW+lo method (WIEN2k).

3. Results and Discussion

In order to investigate a local environment of Zn\(^{2+}\) substituting for Ca\(^{2+}\) in HAp, the experimental Zn-K XANES in comparison with theoretical spectra were displayed in Fig. 2. The almost identical experimental spectrum for the Zn-doped HAp were obtained by Takatsuka et al. and Tang et al. [28,29], and it was also confirmed that the spectral feature for Zn doped into HAp is different from those for zinc phosphate
compounds [28]. Moreover, a Zn-K XANES for 5 mol% Zn$^{2+}$-doped HAp was measured in this study, but there was no obvious difference from the present case of 1 mol% Zn$^{2+}$-doped HAp.

For the XANES calculations, two kinds of situations for substitutional Zn in HAp were considered: (a) an isolated substitution in perfect HAp and (b) substitutions in the presence of the Ca$^{2+}$-vacancy defect complex (see Fig. 1). In the former situation, substitutions at Ca-1 (columnar Ca atoms) [2] and at Ca-2 sites were considered, although the Ca-2 site substitution was theoretically found to be more stable [8,22].

First of all, there was no unambiguous difference in spectrum features between the theoretical spectra obtained by the two different methods. It can be said that the computed results in this study are essential and are not affected by the difference in theoretical background for the electronic structure calculations. When a comparison between theory and experiment was made, however, the theoretical spectra of the substitution models in ‘perfect HAp’ provided obviously different spectral features from the experimental one: for example, the peak splitting between peaks A (9662 eV) and B (9665 eV), and the position of peak C (9674 eV) were not reproduced. Additionally, the prepeak at around 9656 eV was not found for the Ca-1 substitution, while the shoulder-like feature after the peak B in the theoretical spectra did not agree with the experimental one. These discrepancies indicate that Zn$^{2+}$ incorporation in HAp cannot be understood by a simple substitution for Ca in the perfect lattice.

In contrast, for the substitution in ‘Ca deficient HAp,’ two kinds of Ca-2 sites neighbouring the Ca vacancy site, which form the triangle around H$_2$O (denoted by the arrows in Fig. 1(a)), were considered. It is noted that the total energies of the two cases were almost the same with each other and thus no site preference was observed within the present computational accuracy. However, it was found that, when Zn$^{2+}$ substitutes the Ca-2 site shown in Fig. 1(b), the Zn-K XANES shows a quite reasonable agreement
with the experimental spectrum (see the second spectrum from the top of Figs. 2(a) and (b)). Especially, it is worth mentioning that the position of the peak C as well as the separation between A and B were well reproduced. Other spectrum features for the model in Ca deficient HAp, such as the presence of the prepeak at 9656 eV (confirmed from the higher resolution spectrum drawn by the smaller FWHM of 0.5 eV) and the shoulder-like structure after the peak B, were in better agreement with experiment than those for the models in perfect HAp. In this case, Zn was fivefold coordinated to oxygen (the local coordination environment was considerably distorted and thus the bond distance of Zn–O ranged from 0.20 nm to 0.23 nm), and one of the oxygen atoms belonged to the adjacent H$_2$O group. It is noted that the Zn$^{2+}$ substitution at another Ca-2 site considered here (see Fig. 1(a)) exhibited a similar XANES feature (not shown here) with the one at Ca-2 in perfect HAp.

More detailed analyses on the theoretical spectra showed that the pre-edge peak (9658 eV) at Ca-2 in perfect HAp mainly originates from the interaction of Ca with O of an adjacent OH group, and the reduced intensity of the pre-edge peak for Zn in defective HAp is attributed to the covalent interaction of Zn with the H$_2$O group, unlike the interaction with an OH group. In this regard, Miyaji et al. also pointed out the presence of ‘lattice H$_2$O’ and the Ca deficiency in Zn$^{2+}$-doped HAp, whose situation well corresponds to the present argument [7]. It is also noted that substitutional Zn$^{2+}$ and the defect complex have an attractive interaction (the calculated association energy of 0.07 eV) and energetically favour the associated structure as displayed in Fig. 1(b). The defect association results in stabilizing formation of the Ca$^{2+}$-vacancy complex as well as substitutional Zn$^{2+}$. This may also contribute to the increased Ca deficiency of Zn$^{2+}$-doped HAp, as compared to the undoped system, as found experimentally.

Since the experimental and theoretical XANES results demonstrated the presence of the Ca$^{2+}$-vacancy complex in the vicinity of substitutional Zn$^{2+}$, the Ca$^{2+}$-vacancy
defect complex may also play a crucial role for Zn$^{2+}$ incorporation into HAp. Namely, the Ca$^{2+}$-vacancy complex will act as possible substitutional sites for Zn$^{2+}$ incorporation. If this is the case, the Zn$^{2+}$-incorporation reaction can then be written as $(V_{Ca} - 2H_2)(HAp) + Zn^{2+}(aq) \rightarrow Zn_{Ca}(HAp) + 2H^+(aq)$. It should be noted here that two interstitial protons are released from the defect complex into the surrounding solution in the event of Zn$^{2+}$ substitution at the vacant site, as a result of charge neutrality requirement. It can be seen in Fig. 3 that the formation energy of substitutional Zn$^{2+}$ via the vacancy-filling mechanism tends to decrease with rising solution pH and reaches to zero around pH = 10. This indicates that the Zn$^{2+}$ substitution into HAp is thermodynamically stable according to this mechanism and can take place spontaneously in more alkaline conditions. In fact, experimental Zn$^{2+}$ introduction into HAp in the solution-precipitation method was commonly performed in the alkaline solution conditions of around pH =10-11 [6,7,10]. Such a trend was quite different from the simple ion exchange of Ca$^{2+}$ and Zn$^{2+}$ between HAp and solution $(Ca_{Ca}(HAp) + Zn^{2+}(aq) \rightarrow Zn_{Ca}(HAp) + Ca^{2+}(aq))$. In this case, the formation energy of substitutional Zn$^{2+}$ was rather high over the entire solution pH range, even compared to the case via the vacancy-filling mechanism (see Fig. 3), so that the estimated equilibrium concentration of substitutional Zn$^{2+}$ was in an order of ppm. The concentration was far below the experimental data [6,7], indicating that the Zn$^{2+}$ incorporation into HAp cannot be realized by the simple ion-exchange like mechanism. This also supports the important role played by the Ca$^{2+}$-vacancy complex in the Zn$^{2+}$ incorporation.

4. Summary and Conclusions

In summary, the present study showed that Zn$^{2+}$ incorporation into HAp does not simply take place by ion exchange but the Ca$^{2+}$-vacancy defect complexes can act as
plausible atomic sites for substitutional Zn$^{2+}$ in HAp. Since the Ca$^{2+}$-vacancy concentration in Ca deficient HAp commonly obtained through the solution-precipitation method generally ranges within 10 mol% (1.50 < Ca/P < 1.67), it is likely that the Zn$^{2+}$ substitution is also limited to several mol%, as found in previous experiments. Following the Ca$^{2+}$-vacancy filling mechanism, substitutional Zn$^{2+}$ ions may also diffuse through the HAp lattice with the aid of the remaining Ca$^{2+}$-vacancy complexes, which will promote ion exchange occurring between HAp crystals and the surrounding aqueous solution. Such a vacancy-filling mechanism should be closely related to versatile incorporation of trace elements into HAp, which is a key process of biomineralization, leading to the development for high-performance metal-ion doped HAp.

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[29] Tang Y, Chappell HF, Dove MT, Reeder RJ, Lee YJ. Zinc incorporation into
Fig. 1. Atomic structures of defect complexes in (a) pure HAp and (b) Zn$^{2+}$-doped HAp. Ca atoms (green spheres) in the figures all correspond to triangular Ca-2 atoms about the OH arrangement along the c axis. In (a), the Ca$^{2+}$ vacancy at the Ca-2 site is charge-compensated by two protons [18], where the original position of Ca-2 removed to form the vacancy is depicted by ‘V’. Two thick arrows in (a) indicate Ca-2 atoms replaced by Zn$^{2+}$ to simulate Zn-K XANES shown in Fig. 2. In (b), the optimized atomic structure of substitutional Zn$^{2+}$ associated with the Ca$^{2+}$-vacancy defect complex is displayed.
Fig. 2. Experimental Zn-K XANES for Zn\(^{2+}\)-doped HAp in comparison with theoretical ones. The computed spectra obtained by the pseudopotential method (CASTEP) were displayed in (a), while those by the APW+lo method (WIEN2k) in (b). The theoretical spectrum denoted as ‘Ca-def HAp’ in parentheses corresponds to substitutional Zn\(^{2+}\) associated the Ca\(^{2+}\)-vacancy complex, whose atomic structure is depicted in Fig. 1(b). While the calculated spectra denoted as ‘Perfect HAp’ in parentheses indicate isolated substitutional Zn\(^{2+}\) at the Ca-1 and Ca-2 sites of the perfect HAp lattice. The respective computed spectra were drawn by using FWHM of 0.5 eV (thin lines) and 1.67 eV (thick lines), in order to compare them with experiment or to highlight the detailed spectrum features.
Fig. 3. Calculated formation energies of substitutional Zn$^{2+}$ via different formation mechanisms, as a function of solution pH. The mechanism (a) assumes that doped Zn$^{2+}$ simply substitutes Ca$^{2+}$ at Ca-2 in perfect HAp. Then the formation energy tends to decrease with increasing pH, and yet the energy over the pH range results in a negligible defect concentration [8]. The mechanism (b) corresponds to Zn$^{2+}$ occupying the Ca$^{2+}$-vacancy charge-compensated by two protons. By this mechanism, Zn$^{2+}$ ions can be much more easily incorporated into HAp in more alkaline conditions.